QUAD 2-INPUT OR GATE

FEATURES

· Output capability: standard

• I_{CC} category: SSI

GENERAL DESCRIPTION

The 74HC/HCT32 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A. The 74HC/HCT32 provide the 2-input OR function.

CVMDO	DADAMETED	CONDITIONS	TY		
SYMBOL	PARAMETER	CONDITIONS	нс	нст	UNIT
tPHL/ tPLH	propagation delay nA, nB to nY	C _L = 15 pF V _{CC} = 5 V	6	9	ns
Ci	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per gate	notes 1 and 2	16	28	pF

GND = 0 V;
$$T_{amb} = 25$$
 °C; $t_r = t_f = 6$ ns

Notes

1. CPD is used to determine the dynamic power dissipation (PD in μ W):

PD = CPD x VCC^2 x f_i + Σ (CL x VCC^2 x f_o) where:

f; = input frequency in MHz

CL = output load capacitance in pF

VCC = supply voltage in V

 f_0 = output frequency in MHz Σ (C_L x V_{CC}² x f_0) = sum of outputs

2. For HC the condition is VI = GND to VCC

For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5 \text{ V}$

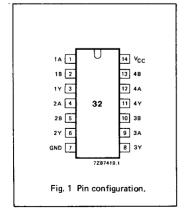
PACKAGE OUTLINES

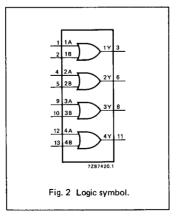
14-lead DIL; plastic (SOT27).

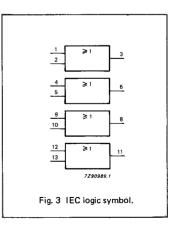
14-lead mini-pack; plastic (SO14; SOT108A).

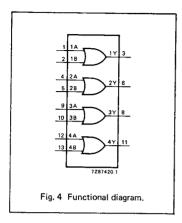
PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION	
1, 4, 9, 12	1A to 4A	data inputs	
2, 5, 10, 13	1B to 4B	data inputs	
3, 6, 8, 11	1Y to 4Y	data outputs	
7	GND	ground (0 V)	
14	Vcc	positive supply voltage	





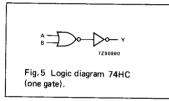


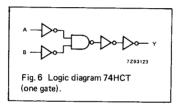


FUNCTION TABLE

INF	PUTS	ОИТРИТ
nA	nB	nΥ
L	L H	L H
H	L	H
н	Н	н

H = HIGH voltage level L = LOW voltage level





DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

ICC category: SSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS	
		74HC									
		+25		-40 to +85		-40 to +125		UNIT	VCC	WAVEFORMS	
		min.	typ.	max.	min.	max.	min.	max.			
^t PHL [/] ^t PLH	propagation delay nA, nB to nY		22 8 6	90 18 15		115 23 20		135 27 23	ns	2.0 4.5 6.0	Fig. 7
^t ТНL/ ^t ТLН	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Fig. 7

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

I_{CC} category: SSI

Note to HCT types

The value of additional quiescent supply current ($\triangle I_{CC}$) for a unit load of 1 is given in the family specifications. To determine $\triangle I_{CC}$ per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
nA, nB	1.20

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_1 = 50 \text{ pF}$

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS	
		+25		-40 to +85		-40 to +125		UNIT	VCC	WAVEFORMS	
		min.	typ.	max.	min.	max.	min.	max.			
tPHL/ tPLH	propagation delay nA, nB to nY		11	24		30		36	ns	4.5	Fig. 7
tTHL/ tTLH	output transition time		7	15		19		22	ns	4.5	Fig. 7

AC WAVEFORMS

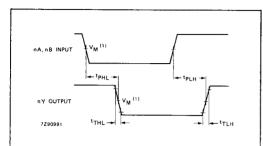


Fig. 7 Waveforms showing the input (nA, nB) to output (nY) propagation delays and the output transition times.

Note to AC waveforms

(1) HC : V_M = 50%; V_1 = GND to V_{CC} . HCT: V_M = 1.3 V; V_1 = GND to 3 V.